

TLP363JF

Triac Drivers

Programmable Controllers

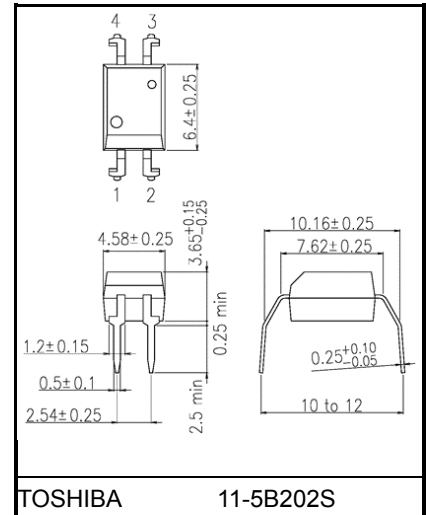
AC-Output Modules

Solid State Relays

TOSHIBA TLP363JF consists of a zero-voltage-crossing turn-on photo-triac optically coupled to an infrared emitting diode in a four-lead plastic DIP package. This product has a greater capacity to withstand external noise than the TLP361JF.

- Peak off-state voltage: 600 V (min)
- Trigger LED current: 10 mA (max)
- On-state current: 100 mA (max)
- Isolation voltage: 5000 Vrms (min)
- Zero crossing function
- UL-recognized: UL 1577, File No.E67349
- cUL-recognized: CSA Component Acceptance Service No.5A
File No.E67349
- CQC approved: GB4943.1, GB8898 Japan Factory
- VDE-approved: EN 60747-5-5 , EN 62368-1 (Note 1)

Unit: mm



TOSHIBA 11-5B202S

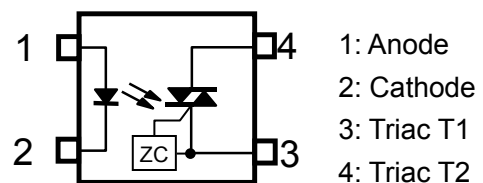
Weight: 0.26 g (typ.)

Note 1: When a VDE approved type is needed, please designate the **Option(D4)**.

•Construction mechanical rating

Creepage distance	8.0 mm (min)
Clearance	8.0 mm (min)
Insulation thickness	0.4 mm (min)

Pin Configuration (top view)



Start of commercial production
2004-01

Absolute Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit
LED	Forward current	I_F	50	mA
	Forward current derating (Ta ≥ 53°C)	$\Delta I_F / ^\circ\text{C}$	-0.7	mA / °C
	Peak forward current (100 μs pulse, 100 pps)	I_{FP}	1	A
	Reverse voltage	V_R	5	V
	Diode power dissipation	P_D	72	mW
	Diode power dissipation derating (Ta ≥ 53°C)	$\Delta P_D / ^\circ\text{C}$	-1.0	mW / °C
	Junction temperature	T_j	125	°C
Detector	Off-state output terminal voltage	V_{DRM}	600	V
	On-state RMS current	Ta = 25°C	100	mA
		Ta = 70°C	50	
	On-state current derating (Ta ≥ 25°C)	$\Delta I_T / ^\circ\text{C}$	-1.1	mA / °C
	Peak on-state current (100 μs pulse, 120 pps)	I_{TP}	2	A
	Peak non-repetitive surge current (Pw = 10 ms)	I_{TSM}	1.2	A
	Output power dissipation	P_o	300	mW
	Output power dissipation derating (Ta ≥ 25°C)	$\Delta P_O / ^\circ\text{C}$	-3.0	mW / °C
	Junction temperature	T_j	115	°C
Storage temperature range	T_{stg}	-55 to 125	°C	
Operating temperature range	T_{opr}	-40 to 100	°C	
Lead soldering temperature (10 s)	T_{sol}	260	°C	
Isolation voltage (AC, 60 s, R.H. ≤ 60 %)	(Note 1) BV_S	5000	Vrms	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Pins 1 and 2 are shorted together and pins 3 and 4 are shorted together.

Recommended Operating Conditions

Characteristic	Symbol	Min	Typ.	Max	Unit
Supply voltage	V_{AC}	—	—	240	V _{ac}
Forward current	I_F	15	20	25	mA
Peak on-state current	I_{TP}	—	—	1	A
Operating temperature	T_{opr}	-25	—	85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	Min	Typ.	Max	Unit
LED	Forward Voltage	V_F	$I_F = 10 \text{ mA}$	1.0	1.15	1.3	V
	Reverse Current	I_R	$V_R = 5 \text{ V}$	—	—	10	μA
	Capacitance	C_T	$V = 0 \text{ V}, f = 1 \text{ MHz}$	—	30	—	pF
Detector	Peak off-state current	I_{DRM}	$V_{DRM} = 600 \text{ V}$	—	10	1000	nA
	Peak on-state voltage	V_{TM}	$I_{TM} = 100 \text{ mA}$	—	1.7	3.0	V
	Holding current	I_H	—	—	0.6	—	mA
	Critical rate of rise of off-state voltage	dv/dt	$V_{in} = 240 \text{ Vrms}, T_a = 85^\circ\text{C}$ (Note 2)	200	500	—	$\text{V}/\mu\text{s}$
	Critical rate of rise of commutating voltage	$dv/dt(c)$	$V_{in} = 60 \text{ Vrms}, I_T = 15 \text{ mA}$ (Note 2)	—	0.2	—	$\text{V}/\mu\text{s}$

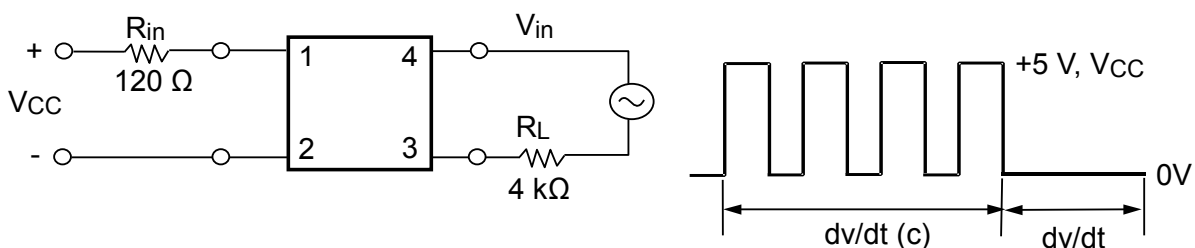
Coupled Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min	Typ.	Max	Unit
Trigger LED current	I_{FT}	$V_T = 3 \text{ V}$	—	—	10	mA
Inhibit voltage	V_{IH}	$I_F = \text{Rated } I_{FT}$	—	—	20	V
Leakage in inhibited state	I_{IH}	$I_F = \text{Rated } I_{FT}$ $V_T = \text{Rated } V_{DRM}$	—	200	600	μA
Turn-on time	t_{ON}	$V_D = 3 \rightarrow 1.5 \text{ V}, R_L = 20 \Omega$ $I_F = \text{Rated } I_{FT} \times 1.5$	—	30	100	μs
Impulse noise durability	V_N	$t_N = 1 \mu\text{s}$, Snubber condition $100 \Omega + 0.033 \mu\text{F}$ (Note.3)	—	2000	—	V

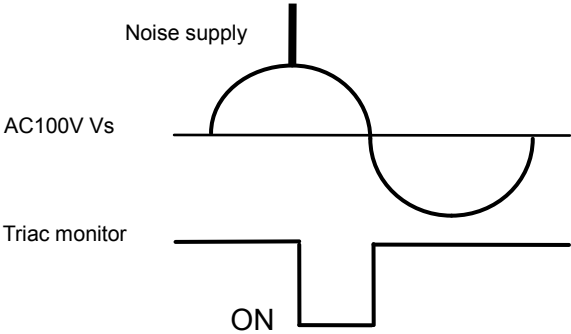
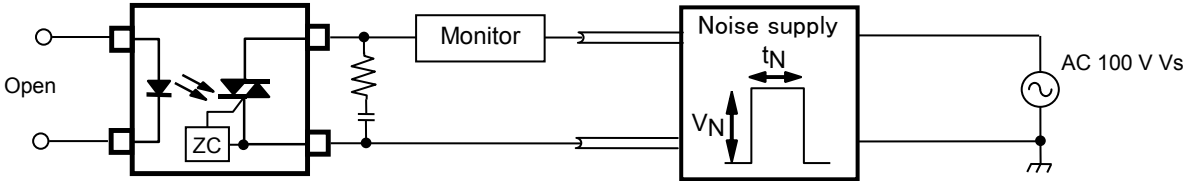
Isolation Characteristics (Ta = 25°C)

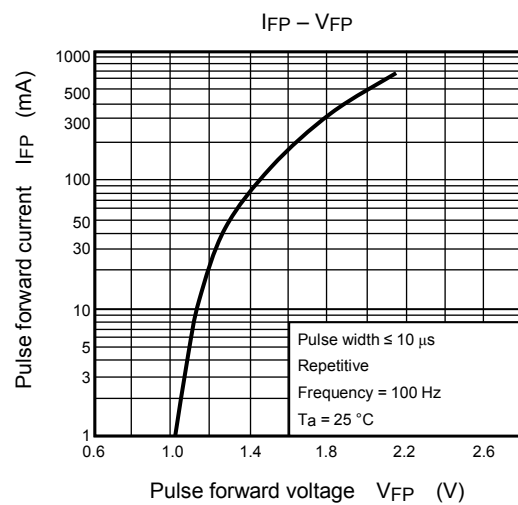
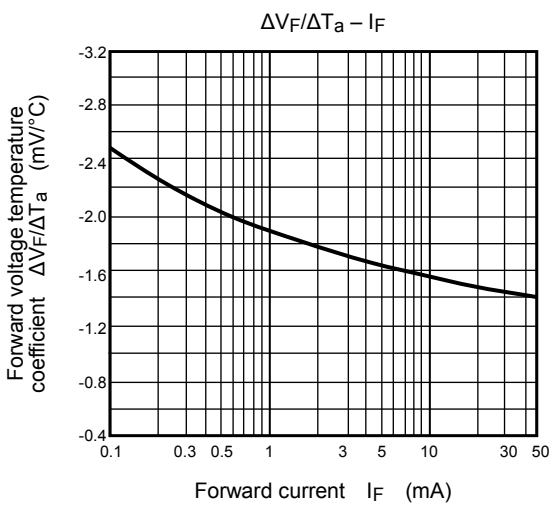
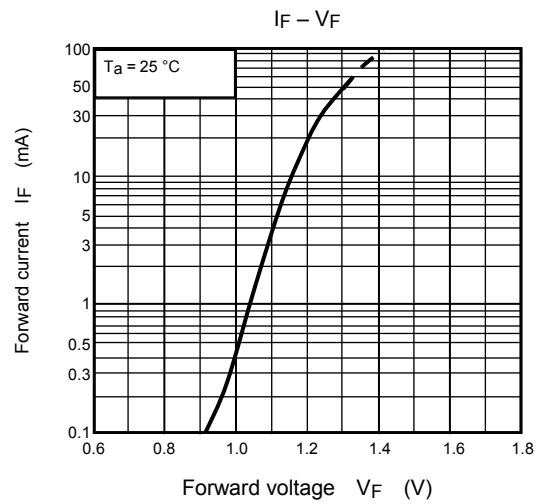
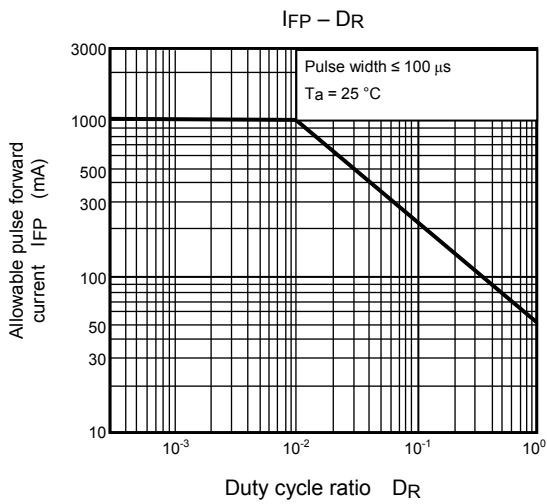
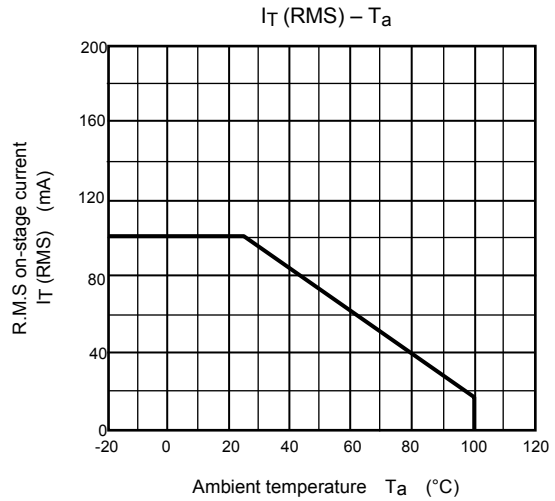
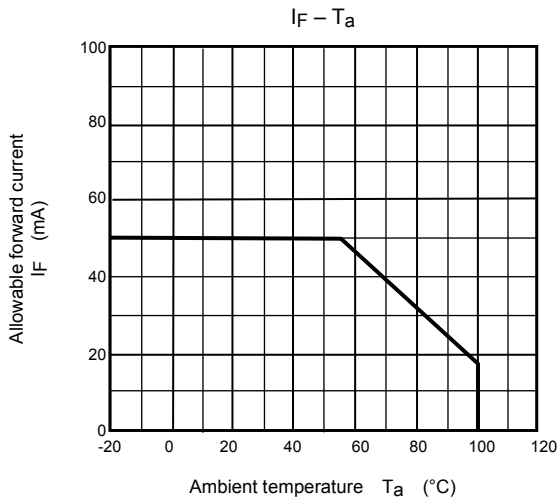
Characteristic	Symbol	Test Condition	Min	Typ.	Max	Unit
Capacitance (input to output)	C_S	$V_S = 0 \text{ V}, f = 1 \text{ MHz}$	—	0.8	—	pF
Isolation resistance	R_S	$V_S = 500 \text{ V}, R.H. \leq 60 \%$	1×10^{12}	10^{14}	—	Ω
Isolation voltage	BV_S	AC, 60 s	5000	—	—	Vrms

Note 2: dv/dt test circuit

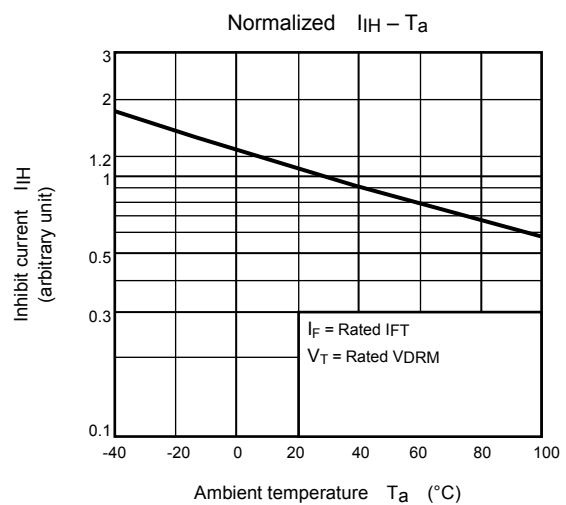
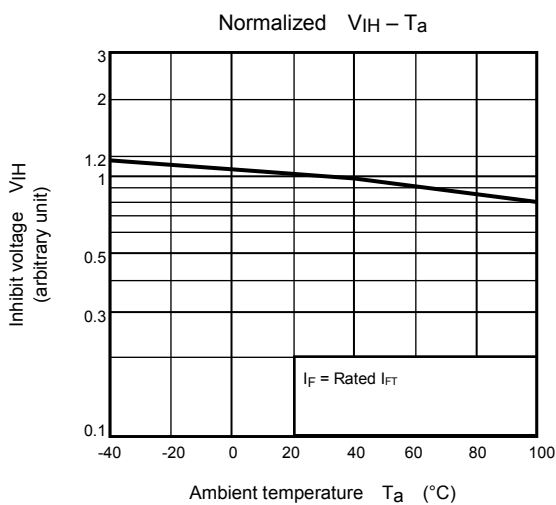
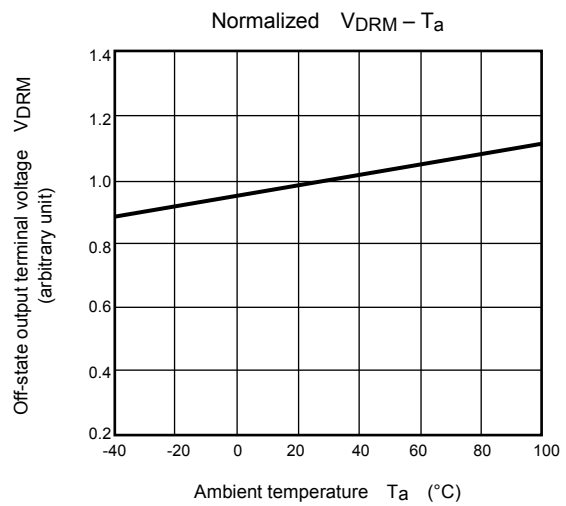
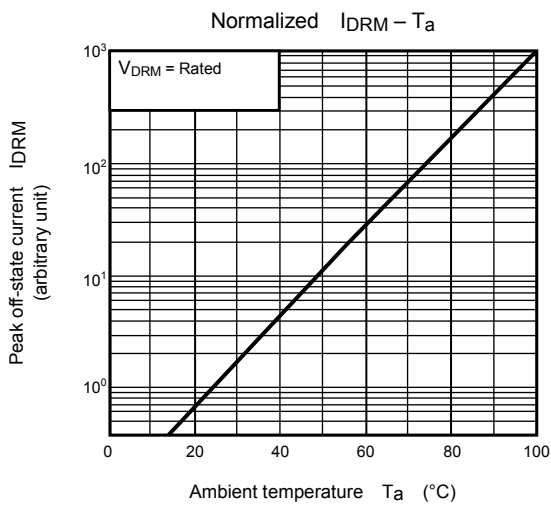
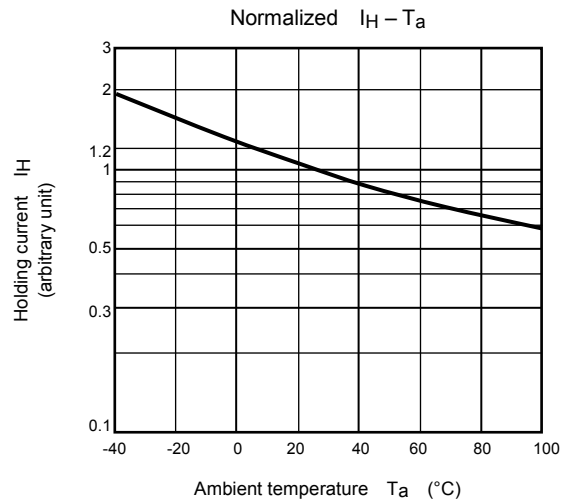
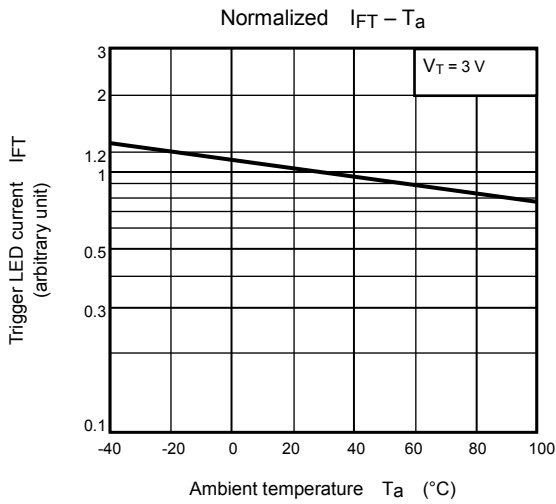


Note 3: impulse noise durability test circuit





NOTE: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



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